Unit: mm

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSVI-H)

TPC8045-H

Switching Regulator Applications Motor Drive Applications DC-DC Converter Applications

- · Small footprint due to a small and thin package
- · High-speed switching
- Small gate charge: Q_{SW} = 23 nC (typ.)
- Low drain-source ON-resistance:

 $R_{DS(ON)} = 2.7 \text{ m}\Omega \text{ (typ.)}$

- High forward transfer admittance: |Y_{fs}| = 67 S (typ.)
- Low leakage current: IDSS = 10 μ A (max) (VDS = 40 V)
- Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characte	eristic	Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	40	V
Drain-gate voltage (R	$R_{GS} = 20 \text{ k}\Omega$	V_{DGR}	40	V
Gate-source voltage		V_{GSS}	±20	V
Drain current	DC (Note 1)	I _D	18	А
Drain current	Pulsed (Note 1)	VGSS ±20 ID 18 IDP 72 PD 1.9 PD 1.0 EAS 150	A	
Drain power dissipati	on (t = 10 s) (Note 2a)	P_{D}	1.9	W
Drain power dissipati	on (t = 10 s) (Note 2b)	P _D	1.0	W
Single-pulse avalance	he energy (Note 3)	E _{AS}	150	mJ
Avalanche current		I _{AR}	18	Α
Repetitive avalanche	energy rc=25°C) (Note 4)	E _{AR}	0.06	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature	range	T _{stg}	-55 to 150	°C

Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

0.595TYP 1.27

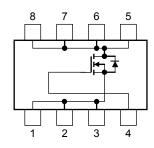
1, 2, 3 SOURCE 4 GATE 5, 6, 7, 8 DRAIN

Weight: 0.085g (typ.)

JEDEC JEITA TOSHIBA

Circuit Configuration

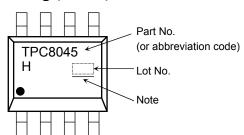
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Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2a)	R _{th (ch-a)}	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	125	°C/W

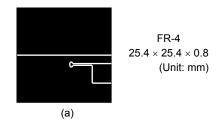
Marking (Note 5)

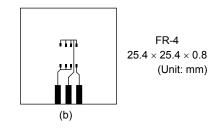


Note: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

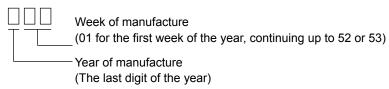
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

- Note 1: Ensure that the channel temperature does not exceed 150°C.
- Note 2: (a) Device mounted on a glass-epoxy board (a)
- (b) Device mounted on a glass-epoxy board (b)





- Note 3: $V_{DD}=24~V,~T_{ch}=25^{\circ}C$ (initial), $L=500~\mu H,~R_{G}=25~\Omega,~I_{AR}=18~A$
- Note 4: Repetitive rating: pulse width limited by maximum channel temperature
- Note 5: * Weekly code: (Three digits)



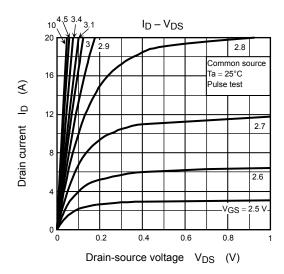
Electrical Characteristics (Ta = 25°C)

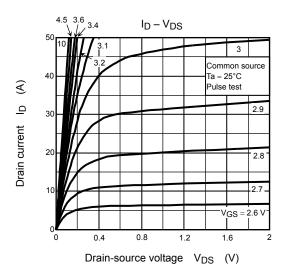
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curi	rent	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cutoff curre	nt	I _{DSS}	V _{DS} = 40 V, V _{GS} = 0 V	_	_	10	μА
Drain agurag bros	ain-source breakdown voltage		I _D = 10 mA, V _{GS} = 0 V	40	_	_	V
Drain-source brea	ikuowii voitage	V _(BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	25	10 0 5 5 3 3 - 2.3 - 3.2 4.4 - 2.7 3.9 .5 67 5800 7540 - 305 445 - 950 1.0 1.5 - 6.4 16 16 16 16 16 16 16 16 16 16 16 90 10 - 10 - 10 - 10 - 10 - 10	v	
Gate threshold vo	ltage	V _{th}	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$	1.3	_	2.3	V
Drain-source ON-resistance		Б	V _{GS} = 4.5 V, I _D = 9 A	_	3.2	4.4	mΩ
Dialii-source Oiv-	resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 9 A	40 — 25 — 1.3 — 2.3 — 3.2 4.4 — 2.7 3.9 33.5 67 — 5800 7540 — 305 445 — 950 — 1.5 — 6.4 — 16 — 16 — 76	1115.2		
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 9 A	33.5	67	_	S
Input capacitance		C _{iss}		_	5800	7540	pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	305	445	
Output capacitance		C _{oss}		_	950	_	
Gate resistance		rg	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	1.0	1.5	Ω
Switching time	Rise time	t _r	V _{GS} 10 V	_	6.4	_	ns
	Turn-on time	t _{on}		_	16	_	
	Fall time	t _f		_	16	_	
	Turn-off time	t _{off}	V _{DD} ≈ 20 V Duty ≤ 1%, t _W = 10 μs	_	76	_	
Total gate charge	otal gate charge		$V_{DD} \approx 32 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 18 \text{ A}$	_	90	_	
(gate-source plus	gate-drain)	Qg	$V_{DD} \approx 32 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 18 \text{ A}$	_	_ 48		
Gate-source charge 1		Q _{gs1}		_	15	_	nC
Gate-drain ("Miller") charge		Q _{gd}	$V_{DD} \approx 32 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 18 \text{ A}$	_	16	_	
Gate switch charge		Q _{SW}	1	_	23	_	

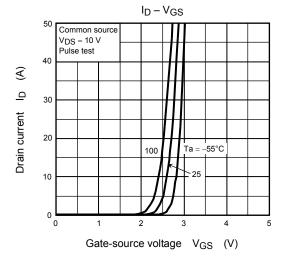
Source-Drain Ratings and Characteristics (Ta = 25°C)

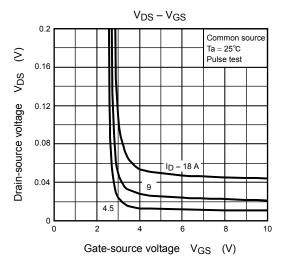
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Peak forward current	Pulse	(Note 1)	I _{FP}	_	_	_	72	Α
Forward voltage (diode)			V_{DSF}	$I_{DR} = 18 \text{ A}, V_{GS} = 0 \text{ V}$		_	-1.2	V

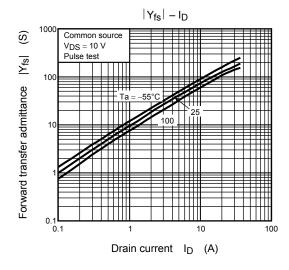
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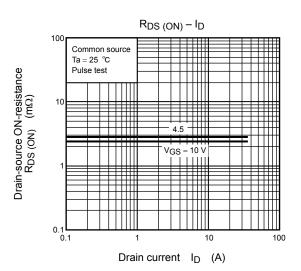


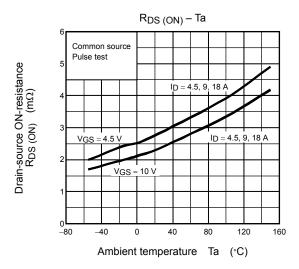


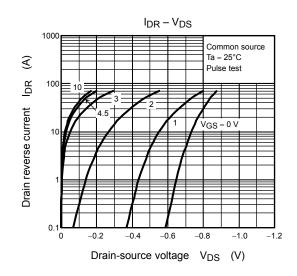


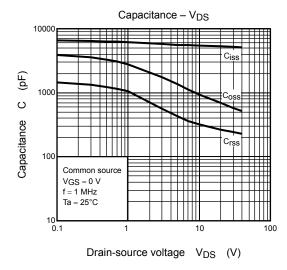


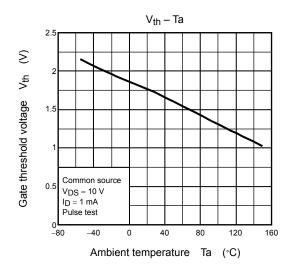


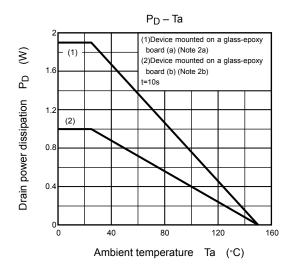


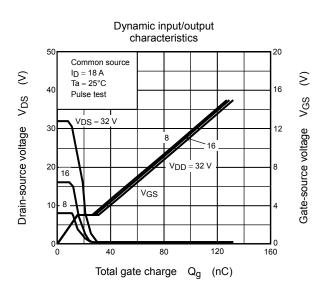


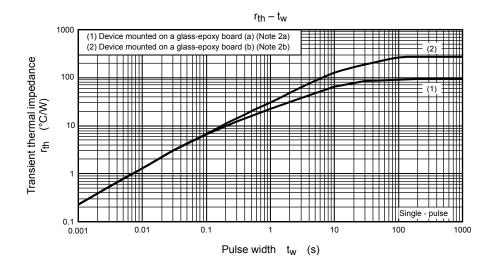


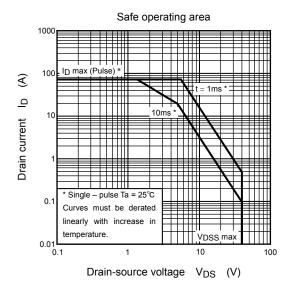












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